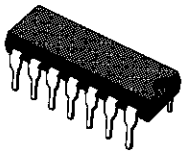
SGS-THOMSON MICROELECTRONICS

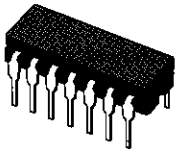
HCC/HCF4047B

LOW-POWER MONOSTABLE/ASTABLE MULTIVIBRATOR

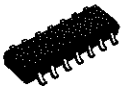
- LOW POWER CONSUMPTION : SPECIAL COS/MOS OSCILLATOR CONFIGURATION
- MONOSTABLE (one-shot) OR ASTABLE (free-running) OPERATION
- TRUE AND COMPLEMENTED BUFFERED OUTPUTS
- ONLY ONE EXTERNAL R AND C REQUIRED
- BUFFERED INPUTS
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- STANDARDIZED, SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V, AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD N° 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"



EY
(Plastic Package)



F
(Ceramic Frit Seal Package)



M1
(Micro Package)

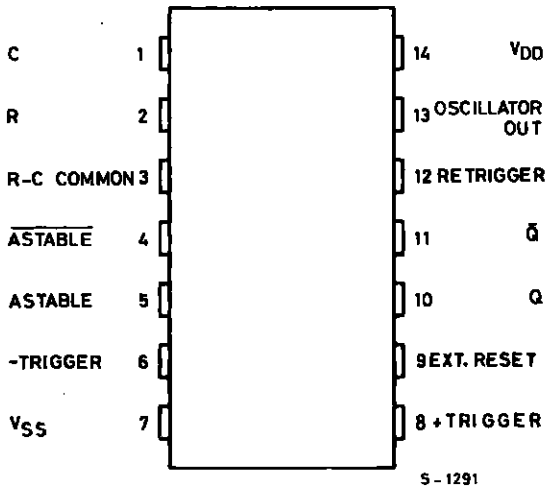


C1
(Plastic Chip Carrier)

ORDER CODES :

HCC4047BF	HCF4047BM1
HCF4047BEY	HCF4047BC1

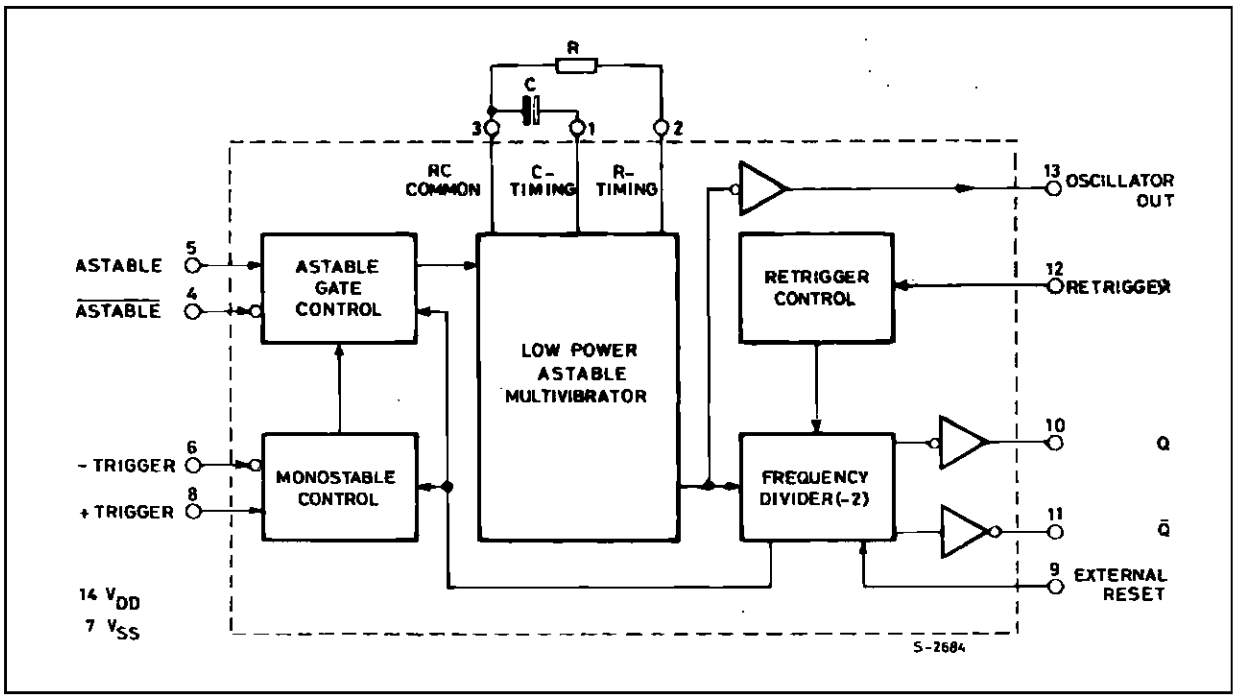
PIN CONNECTIONS



DESCRIPTION

The **HCC4047B** (extended temperature range) and **HCF4047B** (intermediate temperature range) are monolithic integrated circuits, available in 14-lead dual in-line plastic or ceramic package and plastic micropackage. The **HCC/HCF4047B** consists of a gatable astable multivibrator with logic techniques incorporated to permit positive or negative edge-triggered monostable multivibrator action with retriggering and external counting options. Inputs include +TRIGGER -TRIGGER, ASTABLE, ASTABLE, RETRIGGER, and EXTERNAL RESET. Buffered outputs are Q, Q, and OSCILLATOR. In all modes of operation, an external capacitor must be connected between C-Timing and RC-Common terminals, and an external resistor must be connected between the R-Timing and RC-Common terminals. For operating modes see functional terminal connections and application notes.

BLOCK DIAGRAM



FUNCTIONAL TERMINAL CONNECTIONS

Function*	Terminal Connections			Output Pulse From	Output Period or Pulse Width
	to V_{DD}	to V_{SS}	Input Pulse to		
Astable Multivibrator :					
Free Running	4, 5, 6, 14	7, 8, 9, 12	–	10, 11, 13	t_A (10, 11) = 4.40RC
True Gating	4, 6, 14	7, 8, 9, 12	5	10, 11, 13	
Complement Gating	6, 14	5, 7, 8, 9 ,12	4	10, 11, 13	t_A (13) = 2.20RC
Monostable Multivibrator :					
Positive–Edge Trigger	4, 14	5, 6, 7, 9, 12	8	10, 11	
Negative–Edge Trigger	4, 8, 14	5, 7, 9, 12	6	10, 11	
Retriggerable	4, 14	5, 6, 7, 9	8, 12	10, 11	t_M (10, 11) = 2.48RC
External Countdown**	14	5, 6, 7, 8, 9, 12	–	10, 11	

* In all cases external capacitor and resistor between pins, 1, 2 and 3 (see logic diagrams).

** Input pulse to Reset of External Counting Chip.
External Counting Chip Output to pin 4.

ABSOLUTE MAXIMUM RATINGS

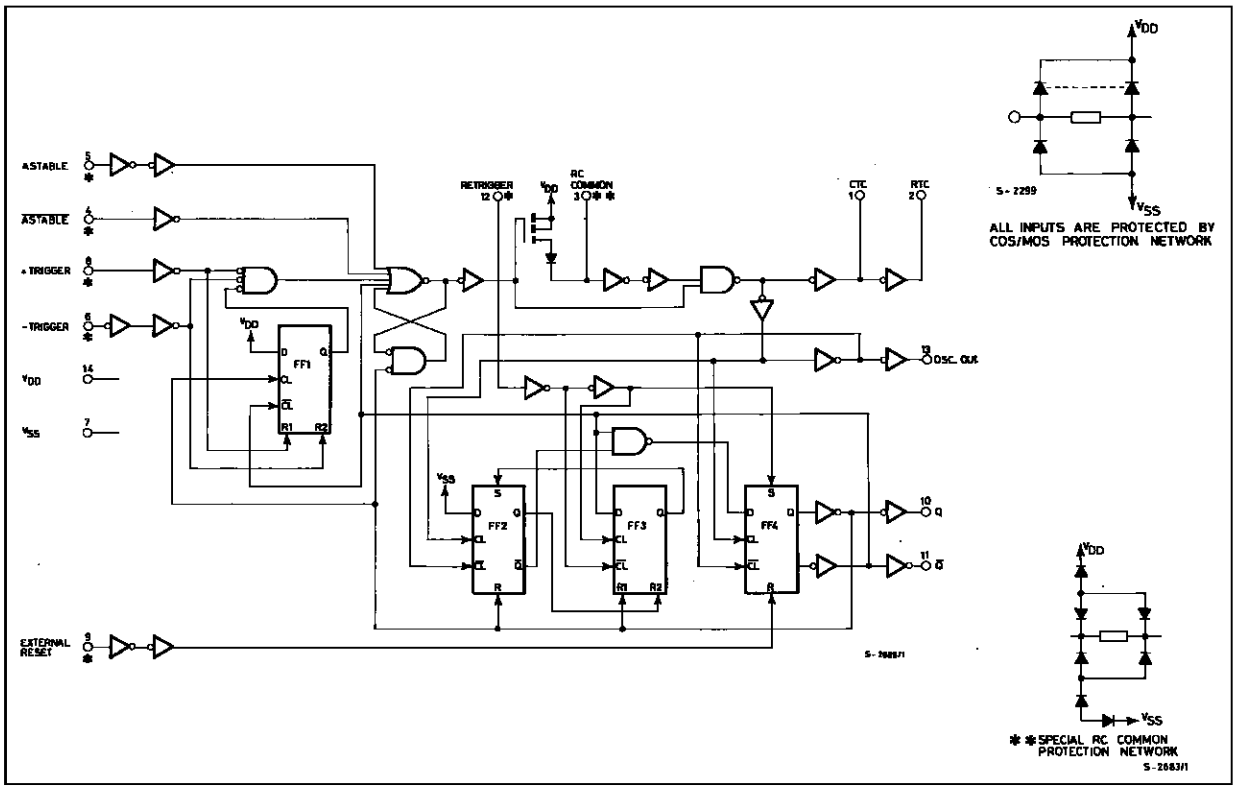
Symbol	Parameter	Value	Unit
V_{DD}*	Supply Voltage : **HCC** Types **HCF** Types	– 0.5 to + 20 – 0.5 to + 18	V V
V_i	Input Voltage	– 0.5 to V_{DD} + 0.5	V
I_I	DC Input Current (any one input)	± 10	mA
P_{tot}	Total Power Dissipation (per package) Dissipation per Output Transistor for T_{op} = Full Package-temperature Range	200 100	mW mW
T_{op}	Operating Temperature : **HCC** Types **HCF** Types	– 55 to + 125 – 40 to + 85	°C °C
T_{stg}	Storage Temperature	– 65 to + 150	°C

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for external periods may affect device reliability.
* All voltage values are referred to V_{SS} pin voltage.

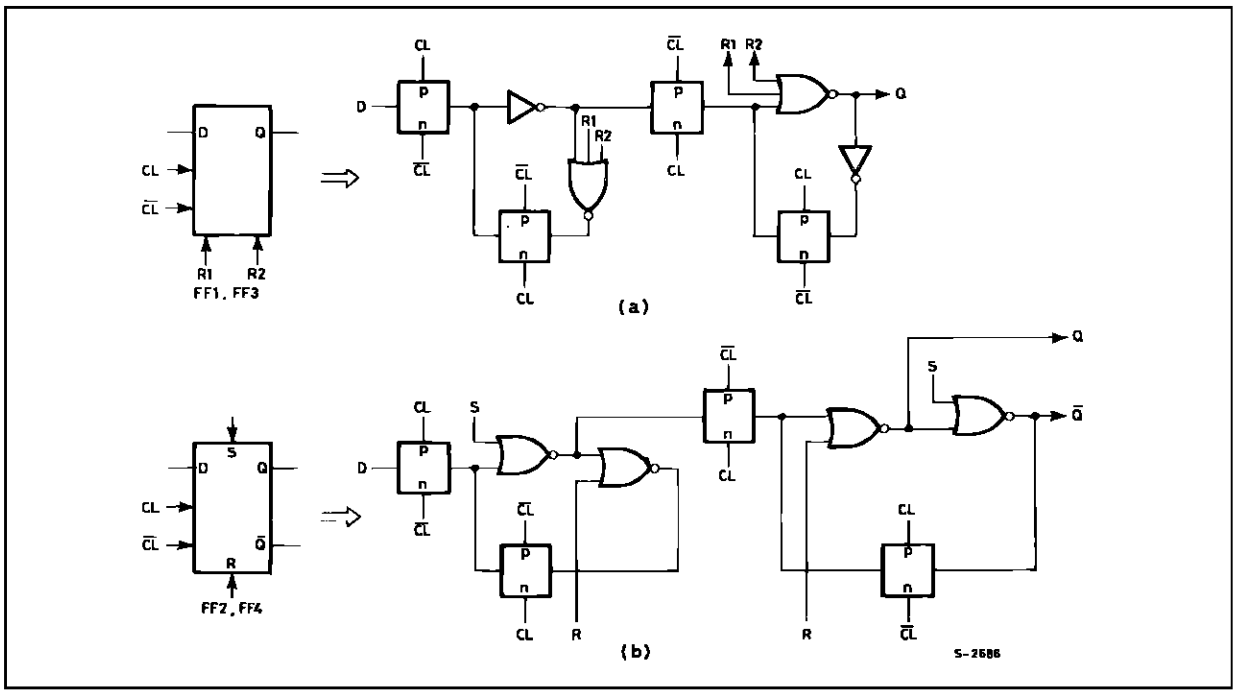
RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage : **HCC** Types **HCF** Types	3 to 18 3 to 15	V V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature : **HCC** Types **HCF** Types	– 55 to + 125 – 40 to + 85	°C °C

LOGIC DIAGRAM



Detail for Flip-flops FF1 and FF3 (a) and for Flip-flops FF2 and FF4 (b).



STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Symbol	Parameter		Test Conditions				Value							Unit
			V_I (V)	V_O (V)	$\|I_O\|$ (μA)	V_{DD} (V)	T_{Low}*		25°C			T_{High}*		
							Min.	Max.	Min.	Typ.	Max.	Min.	Max.	
I_L	Quiescent Current	HCC Types	0/ 5			5		1		0.02	1		30	μA
			0/10			10		2		0.02	2		60	
			0/15			15		4		0.02	4		120	
			0/20			20		20		0.04	20		600	
		HCF Types	0/ 5			5		4		0.02	4		30	
			0/10			10		8		0.02	8		60	
			0/15			15		16		0.02	16		120	
V_{OH}	Output High Voltage		0/ 5		< 1	5	4.95		4.95			4.95		V
			0/10		< 1	10	9.95		9.95			9.95		
			0/15		< 1	15	14.95		14.95			14.95		
V_{OL}	Output Low Voltage		5/0		< 1	5		0.05			0.05		0.05	V
			10/0		< 1	10		0.05			0.05		0.05	
			15/0		< 1	15		0.05			0.05		0.05	
V_{IH}	Input High Voltage			0.5/4.5	< 1	5	3.5		3.5			3.5		V
				1/9	< 1	10	7		7			7		
				1.5/13.5	< 1	15	11		11			11		

* T_{Low} = – 55°C for **HCC** device : – 40°C for **HCF** device.
* T_{High} = + 125°C for **HCC** device : + 85°C for **HCF** device.
The Noise Margin for both "1" and "0" level is : 1V min. with V_{DD} = 5V, 2V min. with V_{DD} = 10V, 2.5V min. with V_{DD} = 15V.

STATIC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter		Test Conditions				Value							Unit
			V_I (V)	V_O (V)	$\|I_O\|$ (μA)	V_{DD} (V)	T_{Low}*		25°C			T_{High}*		
							Min.	Max.	Min.	Typ.	Max.	Min.	Max.	
V_{IL}	Input Low Voltage			4.5/0.5	< 1	5		1.5			1.5		1.5	V
				9/1	< 1	10		3			3		3	
				13.5/1.5	< 1	15		4			4		4	
I_{OH}	Output Drive Current	HCC Types	0/ 5	2.5		5	– 2		– 1.6	– 3.2		– 1.15		mA
			0/ 5	4.6		5	– 0.64		– 0.51	– 1		– 0.36		
			0/10	9.5		10	– 1.6		– 1.3	– 2.6		– 0.9		
			0/15	13.5		15	– 4.2		– 3.4	– 6.8		– 2.4		
		HCF Types	0/ 5	2.5		5	– 1.53		– 1.36	– 3.2		– 1.1		
			0/ 5	4.6		5	– 0.52		– 0.44	– 1		– 0.36		
			0/10	9.5		10	– 1.3		– 1.1	– 2.6		– 0.9		
			0/15	13.5		15	– 3.6		– 3.0	– 6.8		– 2.4		
I_{OL}	Output Sink Current	HCC Types	0/ 5	0.4		5	0.64		0.51	1		0.36		mA
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		HCF Types	0/ 5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I_{IH}, I_{IL}	Input leakage Curent	HCC Types	0/18	Any Input		18		± 0.1		$\pm 10^{-5}$	± 0.1		± 1	μA
		HCF Types	0/15			15		± 0.3		$\pm 10^{-5}$	± 0.3		± 1	
C_I	Input Capacitance			Any Input						5	7.5			pF

* T_{Low} = – 55°C for **HCC** device : – 40°C for **HCF** device.
* T_{High} = + 125°C for **HCC** device : + 85°C for **HCF** device.
The Noise Margin for both "1" and "0" level is : 1V min. with V_{DD} = 5V, 2V min. with V_{DD} = 10V, 2.5V min. with V_{DD} = 15V.

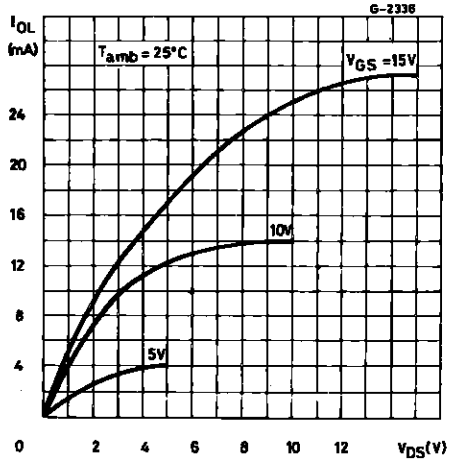
DYNAMIC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C, C_L = 50pF, R_L = 200kΩ, typical temperature coefficient for all V_{DD} values is 0.3%/°C, all input rise and fall times = 20ns)

Symbol	Parameter		Test Conditions	Value				Unit
				V_{DD} (V)	Min.	Typ.	Max.	
t_{PLH}, t_{PHL}	Propagation Delay Time	Astable, $\overline{\text{Astable}}$ to osc. out		5		200	400	ns
				10		100	200	
				15		80	160	
		Astable, $\overline{\text{Astable}}$ to Q, $\overline{Q}$		5		350	700	
				10		175	350	
				15		125	250	
		+ or – Trigger to Q, $\overline{Q}$		5		500	1000	
				10		225	450	
				15		150	300	

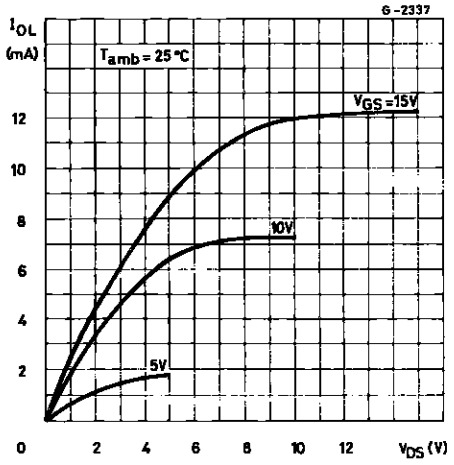
DYNAMIC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter		Test Conditions	Value			Unit
				V_{DD} (V)	Min.	Typ.	Max.	
t_{PLH}, t_{PHL}	Propagation Delay Time	Retrigger to Q, $\overline{Q}$		5		300	600	ns
				10		150	300	
				15		100	200	
		External Reset to Q, $\overline{Q}$		5		250	500	
				10		100	200	
				15		70	140	
t_{THL}, t_{TLH}	Transition Time Osc. Out Q, $\overline{Q}$			5		100	200	
				10		50	100	
				15		40	80	
t_w	Input Pulse Width :	+ Trigger, – Trigger		5		200	400	
				10		80	160	
				15		50	100	
		Reset		5		100	200	
				10		50	100	
				15		30	60	
		Retrigger		5		300	600	
				10		115	230	
				15		75	150	
t_r, t_f	Input Rise and Fall Time All Inputs			5	Unlimited			µs
				10				
				15				
	Q or $\overline{Q}$ Deviation from 50% Duty Factor			5		± 0.5	± 1	%
				10		± 0.5	± 1	
				15		± 0.1	± 0.5	

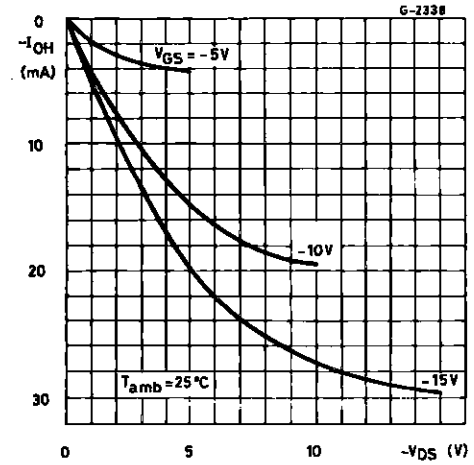
Typical Output Low (sink) Current Characteristics.



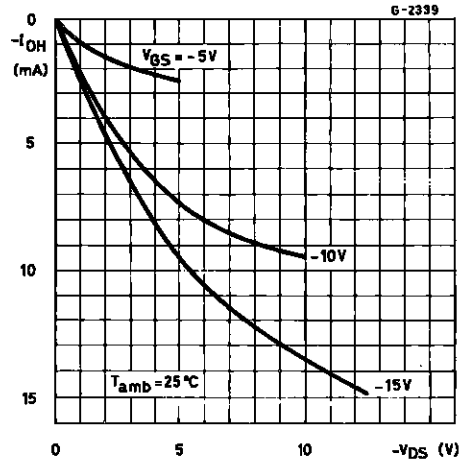
Minimum Output Low (sink) Current Characteristics.



Typical Output High (source) Current Characteristics.



Minimum Output High (source) Current Characteristics.



APPLICATION INFORMATION

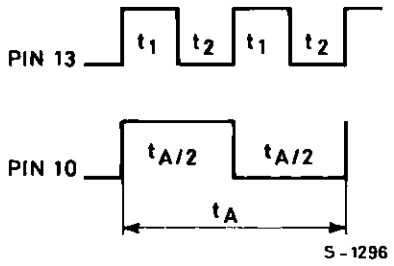
1 - CIRCUIT DESCRIPTION

Astable operation is enabled by a high level on the ASTABLE input. The period of the square wave at the Q and $\overline{Q}$ Outputs in this mode of operation is a function of the external components employed. "True" input pulses on the ASTABLE input or "Complement" pulses on the ASTABLE input allow the circuit to be used as a gatable multivibrator. The OSCILLATOR output period will be half of the Q terminal output in the astable mode. However, a 50% duty cycle is not guaranteed at this output. In the monostable mode, positive-edge triggering is accomplished by application of a leading-edge pulse to the +TRIGGER input and a low level to the –TRIGGER input. For negative-edge triggering, a trailing-edge pulse is applied to the –TRIGGER and a high level is applied to the +TRIGGER. Input pulses may be of any duration relative to the output pulse. The multivibrator can be retriggered (on the leading edge only) by applying a common pulse to both the RETRIGGER and +TRIGGER inputs. In this mode the output pulse remains high as long as the input pulse period is shorter than the period determined by the RC components. An external countdown option can be implemented by coupling "Q" to an external "N" counter and resetting the counter with the trigger pulse. The counter output pulse is fed back to the ASTABLE input and has a duration equal to N times the period of the multivibrator. A high level on the EXTERNAL RESET input assures no output pulse during an "ON" power condition. This input can also be activated to terminate the output pulse at any time. In the monostable mode, a high-level or power-on reset pulse, must be applied to the EXTERNAL RESET whenever V_{DD} is applied.

2 - ASTABLE MODE

The following analysis presents worst-case variations from unit-to-unit as a function of transfer-voltage (V_{TR}) shift (33% – 67% V_{DD}) for free-running (astable) operation.

ASTABLE MODE WAVEFORMS.



$$t_1 = -RC \ln \frac{V_{TR}}{V_{DD} + V_{TR}}$$

$$t_2 = -RC \ln \frac{V_{DD} - V_{TR}}{2V_{DD} - V_{TR}}$$

$$t_A = 2(t_1 + t_2) = -2RC \ln \frac{(V_{TR})(V_{DD} - V_{TR})}{(V_{DD} + V_{TR})(2V_{DD} - V_{TR})}$$

Typ : $V_{TR} = 0.5 \quad V_{DD}$ $t_A = 4.40$ RC

Min : $V_{TR} = 0.33$ V_{DD} $t_A = 4.62$ RC

Max : $V_{TR} = 0.67$ V_{DD} $t_A = 4.62$ RC

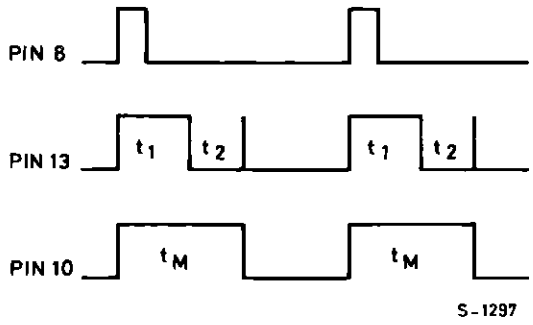
thus if $t_A = 4.40$ RC is used, the maximum variation will be (+ 5.0%, – 0.0%)

In addition to variations from unit-to-unit, the astable period may vary as a function of frequency with respect to V_{DD} and temperature.

3 - MONOSTABLE MODE

The following analysis presents worst-case variations from unit-to-unit as a function of transfer-voltage (V_{TR}) shift (33% – 67% V_{DD}) for one-shot (monostable) operation.

MONOSTABLE WAVEFORMS.



$$t_1 = -RC \ln \frac{V_{TR}}{2V_{DD}}$$

$$t_2 = -RC \ln \frac{V_{DD} - V_{TR}}{2V_{DD} - V_{TR}}$$

$$t_M = (t_1 + t_2) = -RC \ln \frac{(V_{TR})(V_{DD} - V_{TR})}{(2V_{DD} - V_{TR})(2V_{DD})}$$

Where t_M = monostable mode pulse width. Values for t_M are as follows :

Typ : $V_{TR} = 0.5 \quad V_{DD}$ $t_M = 2.48$ RC

Min : $V_{TR} = 0.33$ V_{DD} $t_M = 2.71$ RC

Max : $V_{TR} = 0.67$ V_{DD} $t_M = 2.48$ RC

Thus if $t_M = 2.48$ RC is used, the maximum variation will be (+ 9.3%, – 0.0%).

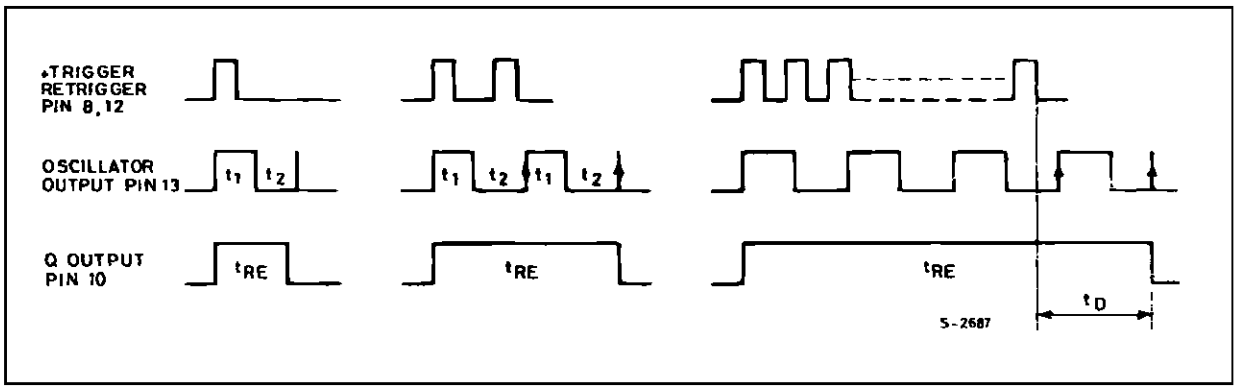
Note : In the astable mode, the first positive half cycle has a duration of T_M ; succeeding durations are $t_A/2$.

In addition to variations from unit to unit, the monostable pulse width may vary as a function of frequency with respect to V_{DD} and temperature.

4 - RETRIGGER MODE

The **HCC/HCF4047B** can be used in the retrigger mode to extend the output-pulse duration, or to compare the frequency of an input signal with that of the internal oscillator. In the retrigger mode the input pulse is applied to terminals 8 and 12, and the output is taken from terminal 10 or 11. As shown in fig. A normal monostable action is obtained when one retrigger pulse is applied. Extended pulse duration is obtained when more than one pulse is applied. For two input pulses, $t_{RE} = t_1' + t_1 + 2t_2$. For more than two pulses, t_{RE} (Q OUTPUT) terminates at some variable time t_D after the termination of the last retrigger pulse. t_D is variable because t_{RE} (Q OUTPUT) terminates after the second positive edge of the oscillator output appears at flip-flop 4 (see logic diagram).

Figure A : Retrigger-mode Waveforms.



5 - EXTERNAL COUNTER OPTION

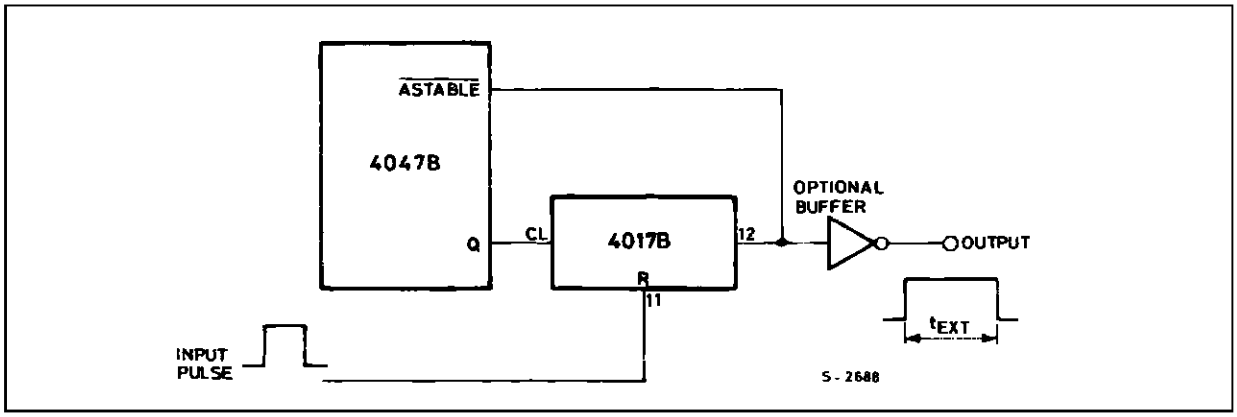
Time t_M can be extended by any amount with the use of external counting circuitry. Advantages include digitally controlled pulse duration, small timing capacitors for long time periods, and extremely fast recovery time.

A typical implementation is shown in fig. B. The pulse duration at the output is

$$t_{ext} = (N - 1)\ (t_A) + (t_M + t_A/2)$$

Where t_{ext} = pulse duration of the circuitry, and N is the number of counts used.

Figure B : Implementation of External Counter Option.



6 - POWER CONSUMPTION

In the standby mode (Monostable or Astable), power dissipation will be a function of leakage current in the circuit, as shown in the static electrical characteristics. For dynamic operation, the power needed to charge the external timing capacitor C is given by the following formula :

Astable Mode : $P = 2CV^2f$. (Output at Pin 13)

$P = 4CV^2f$. (Output at Pin 10 and 11)

Monostable Mode : $P = \dfrac{(2.9CV^2)\ (\text{Duty Cycle})}{T}$

(Output at Pin 10 and 11)

The circuit is designed so that most of the total power is consumed in the external components. In practice, the lower the values of frequency and voltage used, the closer the actual power dissipation will be to the calculated value.

Because the power dissipation does not depend on R, a design for minimum power dissipation would be a small value of C. The value of R would depend on the desired period (within the limitations discussed above).

7 - TIMING-COMPONENT LIMITATIONS

The capacitor used in the circuit should be non-polarized and have low leakage (i.e. the parallel resistance of the capacitor should be an order of magnitude greater than the external resistor used). Three is no upper or lower limit for either R or C value to maintain oscillation.

However, in consideration of accuracy, C must be much larger than the inherent stray capacitance in

the system (unless this capacitance can be measured and taken into account). R must be much larger than the COS/MOS "ON" resistance in series with it, which typically is hundreds of ohms. In addition, with very large values of R, some short-term instability with respect to time may be noted.

The recommended values for these components to maintain agreement with previously calculated formulas without trimming should be :

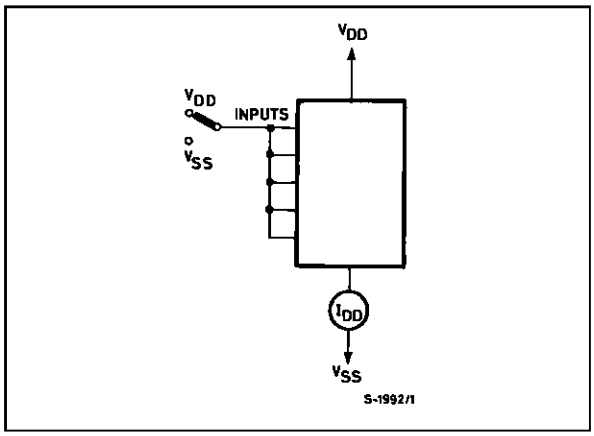
$C \geq 100pF$, up to any practical value, for astable modes ;

$C \geq 1000pF$, up to any practical value, for monostable modes.

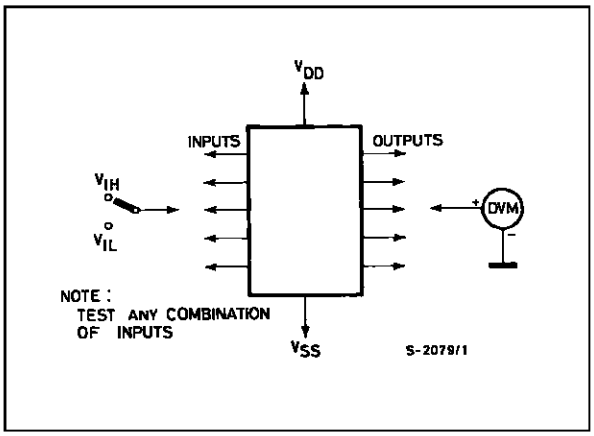
$10K\Omega \leq R \leq 1M\Omega$.

TEST CIRCUITS

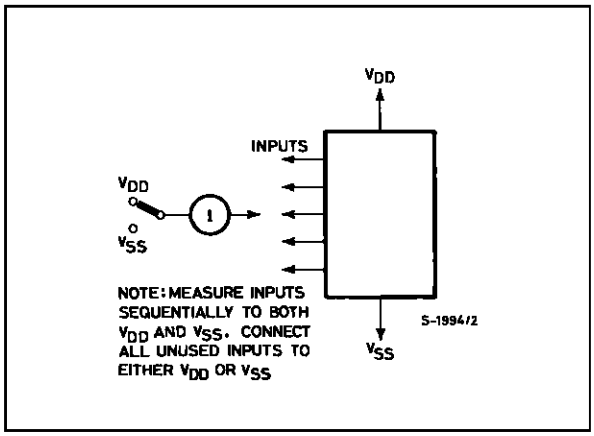
Quiescent Device Current.



Input Voltage.

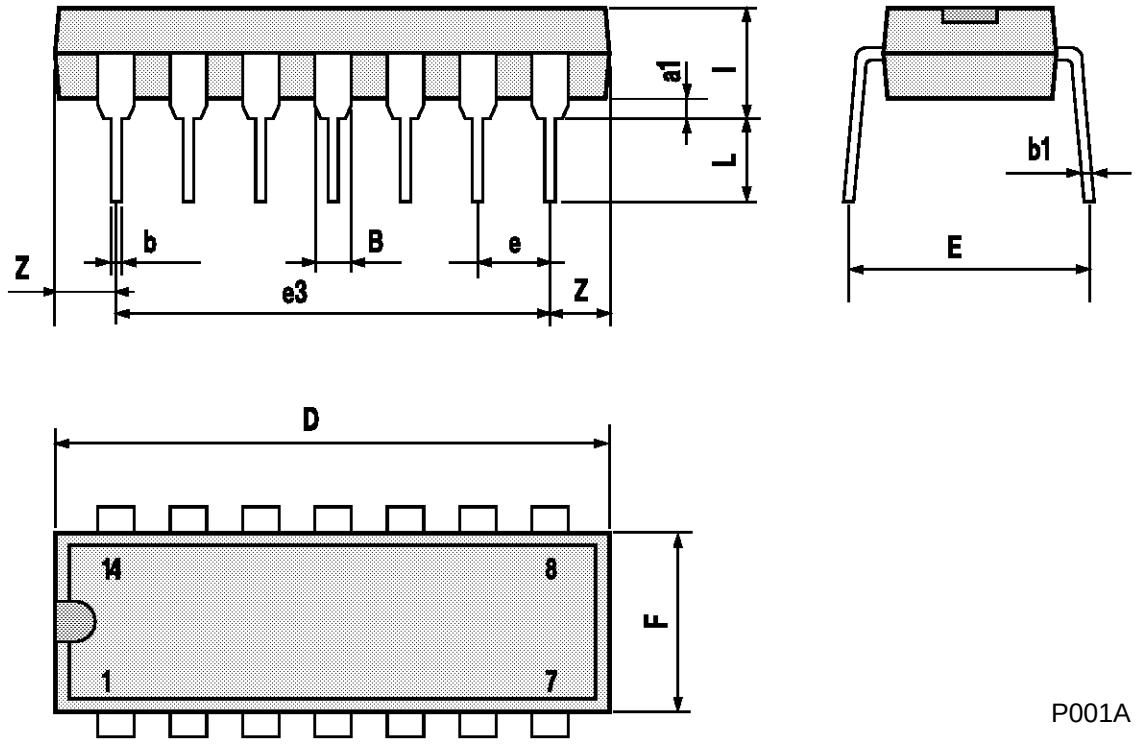


Input Current.



Plastic DIP14 MECHANICAL DATA

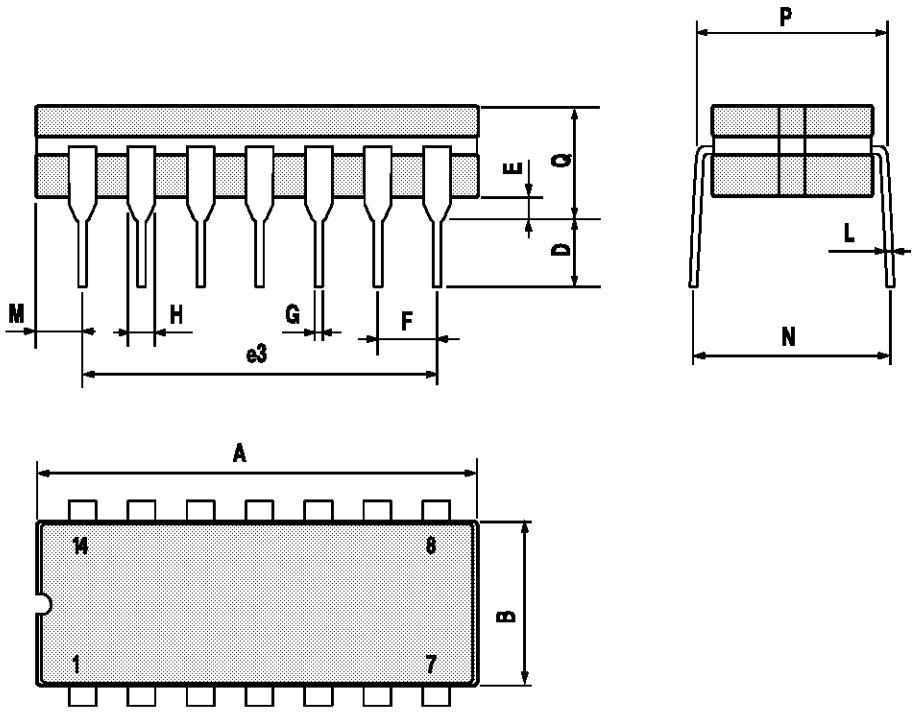
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



P001A

Ceramic DIP14/1 MECHANICAL DATA

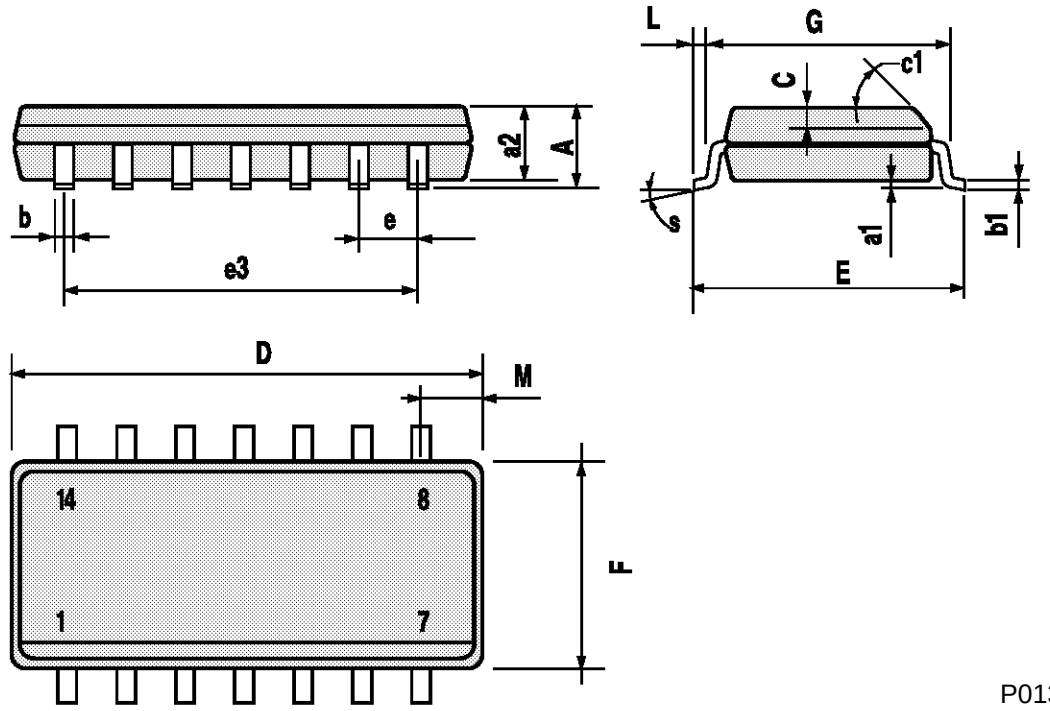
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7.0			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		15.24			0.600	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	1.52		2.54	0.060		0.100
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



P053C

SO14 MECHANICAL DATA

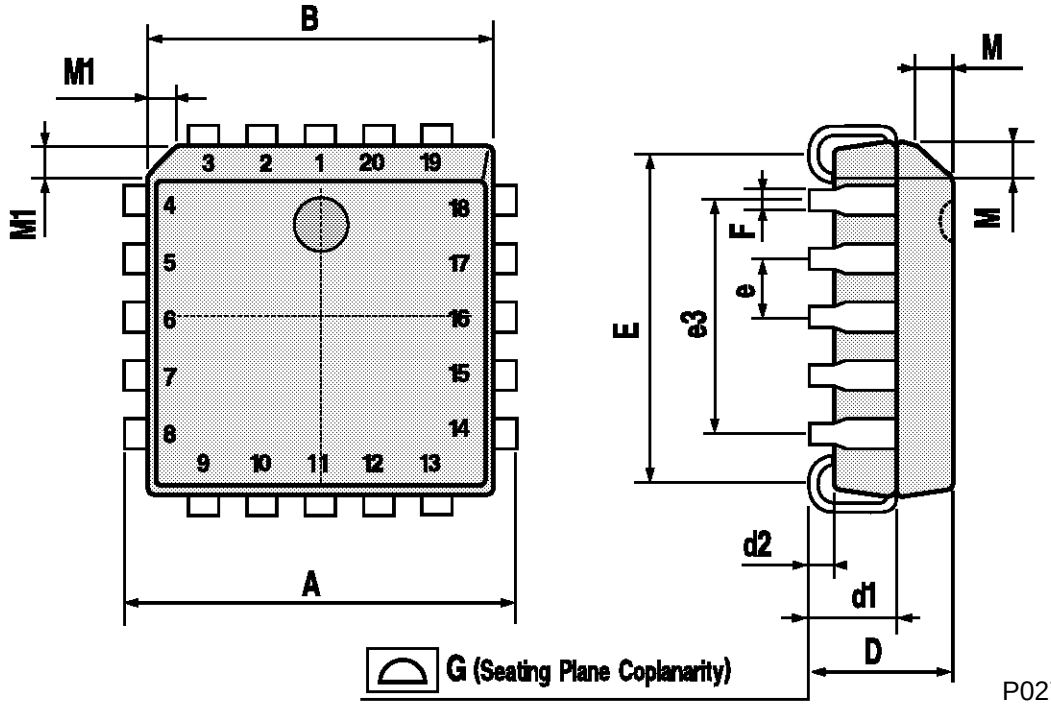
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



P013G

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



P027A

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